

Product data sheet

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Semiconductor Compiance

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Juntion
- Ideal for automated placement
- Fast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SOD-123FL
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight:15mg 0.00048oz

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	FR101 F1	FR102 F2	FR103 F3	FR104 F4	FR105 F5	FR106 F6	FR107 F7	Units
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at Ta = 65 °C	I _{F(AV)}	1.0					A		
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	30					А		
Maximum Instantaneous Forward Voltage at 1 A	VF	1.3					V		
Maximum DCReverse Current Ta = 25 °C at Rated DCBlocking Voltage Ta =125 ℃	I _R	1 50					μA		
Maximum Reverse Recovery Time ¹⁾	t _{rr}	150 25			250	500		ns	
Typical Junction Capacitance ²⁾	Cj	15					pF		
Operating and Storage Temperature Range	Tj, T _{stg}	-55 ~ +150					°C		

1) Measured with I_F = 0.5 A, I_R = 1 A, I_{\rm rr} = 0.25 A

2) Measured at 1MHz and applied reverse voltage of 4V D.C

1 2

Cathode

Anode

DESCRIPTION

PINNING

PIN

1

2

SOD-123FL





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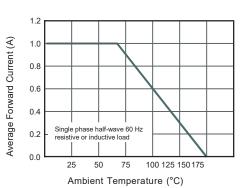


Fig.1 Forward Current Derating Curve

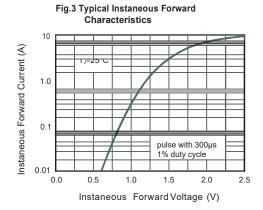


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current Peak Forward Surage Current (A) 30 25 20 15 10 8.3 ms Single Half Sine Wave (JEDEC Method) 05 1 00 10 100 1 Number of Cycles

Fig.2 Typical Reverse Characteristics

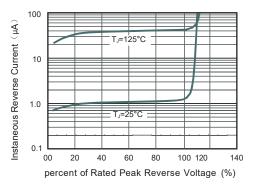
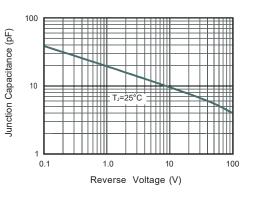


Fig.4 Typical Junction Capacitance

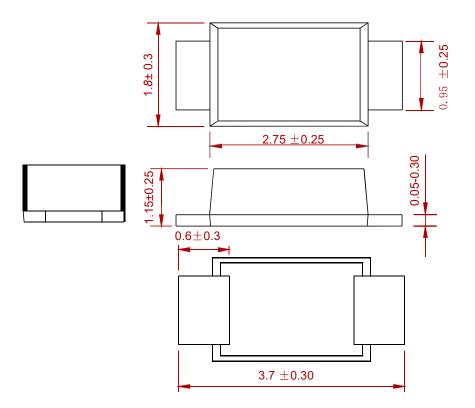






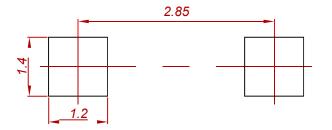
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PACKAGE MECHANICAL DATA



Dimensions in millimeters

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
FR101 THRU FR107	SOD-123FL	3000





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